NSN 5962-01-424-8784

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
E-3 esm grp b, awacs program
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Terminal Surface Treatment:
Solder
Product Name:
Cmos, programmed uv erasable, c22v10
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds input to output access
Memory Device Type:
Pal
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0